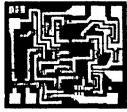


OPERATIONAL AMPLIFIERS

MC1709 MC1709C

MONOLITHIC OPERATIONAL AMPLIFIER



... designed for use as a summing amplifier, integrator, or amplifier with operating characteristics as a function of the external feedback components.

- High-Performance Open Loop Gain Characteristics
 $A_{VOL} = 45,000$ typical
- Low Temperature Drift – $\pm 3.0 \mu\text{V}/^\circ\text{C}$
- Large Output Voltage Swing – $\pm 14 \text{ V}$ typical @ $\pm 15 \text{ V}$ Supply
- Low Output Impedance – $Z_{OUT} = 150$ ohms typical

OPERATIONAL AMPLIFIER INTEGRATED CIRCUIT MONOLITHIC SILICON

G SUFFIX
METAL PACKAGE
CASE 601
TO-99



L SUFFIX
CERAMIC PACKAGE
CASE 632
TO-116

P2 SUFFIX
PLASTIC PACKAGE
CASE 605
TO-116
(MC1709C only)



F SUFFIX
CERAMIC PACKAGE
CASE 606
TO-91

P1 SUFFIX
PLASTIC PACKAGE
CASE 626
(MC1709C only)



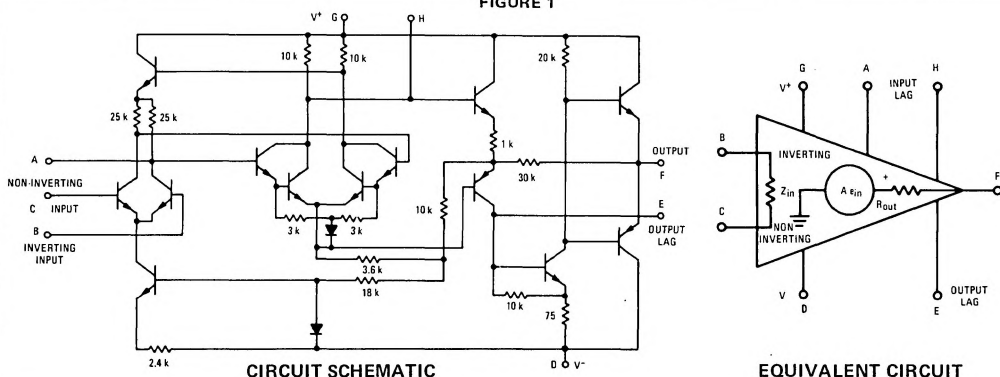
PIN CONNECTIONS

Schematic	A	B	C	D	E	F	G	H
"G" & "P1" Packages	1	2	3	4	5	6	7	8
"F" Package	2	3	4	5	6	7	8	9
"P2" & "L" Packages	3	4	5	6	9	10	11	12

MAXIMUM RATINGS ($T_A = +25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit	
Power Supply Voltage	V^+	+18	Vdc	
	V^-	-18	Vdc	
Differential Input Signal	V_{in}	± 5.0	Volts	
Common Mode Input Swing	CMV_{in}	$\pm V^+$	Volts	
Load Current	I_L	10	mA	
Output Short Circuit Duration	t_S	5.0	s	
Power Dissipation (Package Limitation)	P_D	Metal Can	680	mW
		Derate above $T_A = +25^\circ\text{C}$	4.6	mW/ $^\circ\text{C}$
		Flat Package	500	mW
		Derate above $T_A = +25^\circ\text{C}$	3.3	mW/ $^\circ\text{C}$
		Plastic Dual In-Line Packages	625	mW
		Derate above $T_A = +25^\circ\text{C}$	5.0	mW/ $^\circ\text{C}$
Ceramic Dual In-Line Package	P_D	750	mW	
		Derate above $T_A = +25^\circ\text{C}$	6.0	mW/ $^\circ\text{C}$
Operating Temperature Range	MC1709	T_A	-55 to $+125$	$^\circ\text{C}$
	MC1709C		0 to $+75$	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	Metal and Ceramic Packages	-65 to $+150$	$^\circ\text{C}$
		Plastic Packages	-55 to $+125$	$^\circ\text{C}$

FIGURE 1



MC1709, MC1709C (continued)

ELECTRICAL CHARACTERISTICS ($V^+ = +15$ Vdc, $V^- = -15$ Vdc, $T_A = +25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	MC1709			MC1709C			Unit	
		Min	Typ	Max	Min	Typ	Max		
Open Loop Voltage Gain ($R_L = 2.0$ k Ω) ($V_O = \pm 10$ V, $T_A = T_{low}$ to T_{high}) ^②	A_{VOL}	25,000	45,000	70,000	15,000	45,000	—	—	
Output Impedance ($f = 20$ Hz)	Z_{out}	—	150	—	—	150	—	Ω	
Input Impedance ($f = 20$ Hz)	Z_{in}	150	400	—	50	250	—	k Ω	
Output Voltage Swing ($R_L = 10$ k Ω) ($R_L = 2.0$ k Ω)	V_O	± 12 ± 10	± 14 ± 13	— —	± 12 ± 10	± 14 ± 13	— —	V_{peak}	
Input Common-Mode Voltage Swing	CMV_{in}	± 8	± 10	—	± 8.0	± 10	—	V_{peak}	
Common-Mode Rejection Ratio ($f = 20$ Hz)	CM_{rej}	70	90	—	65	90	—	dB	
Input Bias Current ($T_A = +25^\circ\text{C}$) ($T_A = T_{low}$)	I_b	— —	0.2 0.5	0.5 1.5	— —	0.3 —	1.5 2.0	μA	
Input Offset Current ($T_A = +25^\circ\text{C}$) ($T_A = T_{low}$) ($T_A = T_{high}$)	$ I_{io} $	— — —	0.05 — —	0.2 0.5 0.2	— — —	0.1 — —	0.5 0.75 0.75	μA	
Input Offset Voltage ($T_A = +25^\circ\text{C}$) ($T_A = T_{low}$ to T_{high})	$ V_{io} $	— —	1.0 —	5.0 6.0	— —	2.0 —	7.5 10	mV	
Step Response { Gain = 100, 5.0% overshoot, $R_1 = 1.0$ k Ω , $R_2 = 100$ k Ω , $R_3 = 1.5$ k Ω , $C_1 = 100$ pF, $C_2 = 3.0$ pF	dV_{out}/dt ①	t_f	—	0.8	—	—	0.8	—	μs
{ $R_1 = 1.0$ k Ω , $R_2 = 10$ k Ω , $R_3 = 1.5$ k Ω , $C_1 = 500$ pF, $C_2 = 20$ pF		t_{pd}	—	0.38	—	—	0.38	—	μs
		dV_{out}/dt	—	12	—	—	12	—	V/ μs
{ Gain = 10, 10% overshoot, $R_1 = 1.0$ k Ω , $R_2 = 10$ k Ω , $R_3 = 1.5$ k Ω , $C_1 = 500$ pF, $C_2 = 20$ pF	dV_{out}/dt ①	t_f	—	0.6	—	—	0.6	—	μs
{ Gain = 1, 5.0% overshoot, $R_1 = 10$ k Ω , $R_2 = 10$ k Ω , $R_3 = 1.5$ k Ω , $C_1 = 5000$ pF, $C_2 = 200$ pF		t_{pd}	—	0.34	—	—	0.34	—	μs
		dV_{out}/dt	—	1.7	—	—	1.7	—	V/ μs
{ Gain = 1, 5.0% overshoot, $R_1 = 10$ k Ω , $R_2 = 10$ k Ω , $R_3 = 1.5$ k Ω , $C_1 = 5000$ pF, $C_2 = 200$ pF	dV_{out}/dt ①	t_f	—	2.2	—	—	2.2	—	μs
Average Temperature Coefficient of Input Offset Voltage ($R_S = 50$ Ω , $T_A = T_{low}$ to T_{high}) ($R_S \leq 10$ k Ω , $T_A = T_{low}$ to T_{high})		t_{pd}	—	1.3	—	—	1.3	—	μs
		dV_{out}/dt	—	0.25	—	—	0.25	—	V/ μs
DC Power Dissipation (Power Supply = ± 15 V, $V_O = 0$)	P_D	—	80	165	—	80	200	mW	
Positive Supply Sensitivity (V^- constant)	S^+	—	25	150	—	25	200	$\mu\text{V}/\text{V}$	
Negative Supply Sensitivity (V^+ constant)	S^-	—	25	150	—	25	200	$\mu\text{V}/\text{V}$	

① $dV_{out}/dt =$ Slew Rate

② $T_{high} = +75^\circ\text{C}$ for MC1709C,
 $+125^\circ\text{C}$ for MC1709

$T_{low} = 0^\circ\text{C}$ for MC1709C,
 -55°C for MC1709

TYPICAL CHARACTERISTICS

FIGURE 2 — TEST CIRCUIT
 $V^+ = +15$ Vdc, $V^- = -15$ Vdc, $T_A = +25^\circ\text{C}$

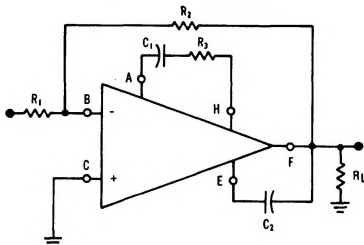


Fig. No.	Curve No.	Test Conditions				
		R_1 (Ω)	R_2 (Ω)	R_3 (Ω)	C_1 (pF)	C_2 (pF)
3	1	10 k	10 k	1.5 k	5.0 k	200
	2	10 k	100 k	1.5 k	500	20
	3	10 k	1.0 M	1.5 k	100	3.0
	4	1.0 k	1.0 M	0	10	3.0
4	1	1.0 k	1.0 M	0	10	3.0
	2	10 k	1.0 M	1.5 k	100	3.0
	3	10 k	100 k	1.5 k	500	20
	4	10 k	10 k	1.5 k	5.0 k	200
5	1	0	∞	1.5 k	5.0 k	200
	2	0	∞	1.5 k	500	20
	3	0	∞	1.5 k	100	3.0
	4	0	∞	0	10	3.0

TYPICAL CHARACTERISTICS (continued)
 ($V^+ = +15$ Vdc, $V^- = -15$ Vdc, $T_A = +25^\circ\text{C}$ unless otherwise noted.)

FIGURE 3 – LARGE SIGNAL SWING
 versus FREQUENCY

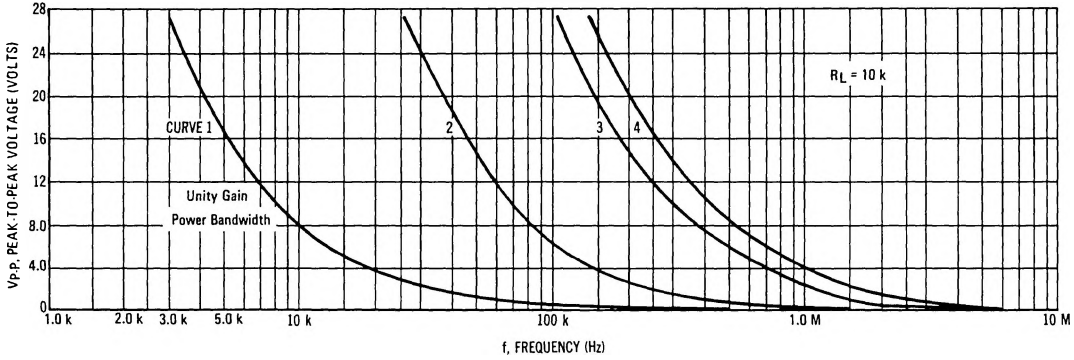


FIGURE 4 – VOLTAGE GAIN
 versus FREQUENCY

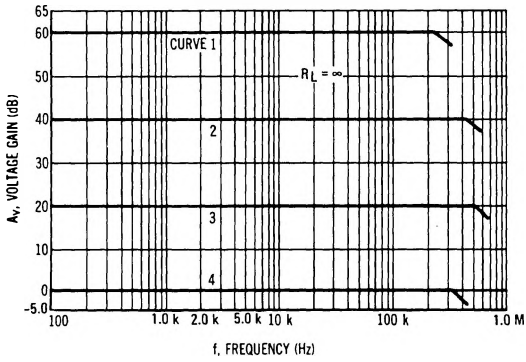


FIGURE 5 – OPEN LOOP
 VOLTAGE GAIN versus FREQUENCY

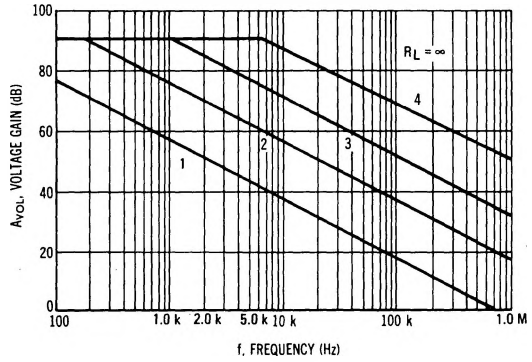


FIGURE 6 – VOLTAGE GAIN
 versus POWER SUPPLY VOLTAGE

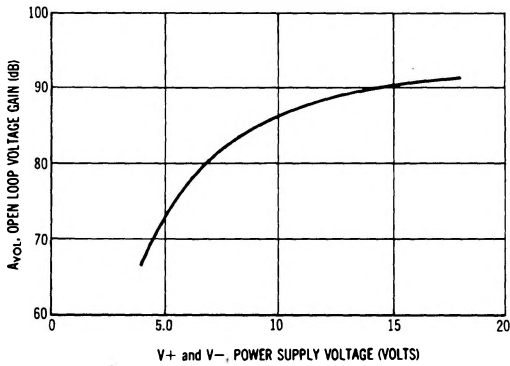
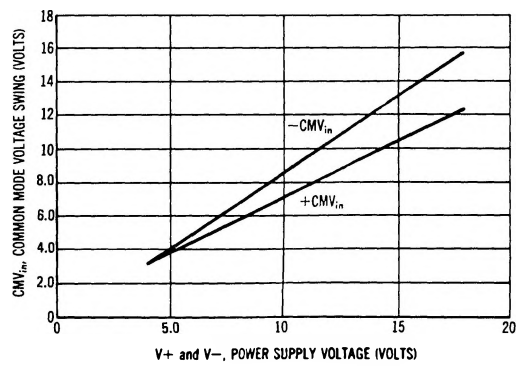


FIGURE 7 – COMMON SWING
 versus POWER SUPPLY VOLTAGE



MC1709, MC1709C (continued)

TYPICAL CHARACTERISTICS (continued)

($V^+ = +15$ Vdc, $V^- = -15$ Vdc, $T_A = +25^\circ\text{C}$ unless otherwise noted.)

FIGURE 8 – POWER DISSIPATION versus POWER SUPPLY VOLTAGE

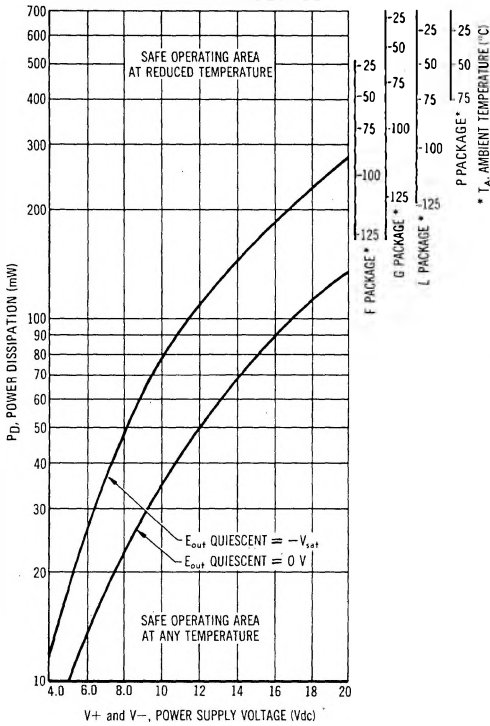


FIGURE 9 – INPUT OFFSET VOLTAGE versus TEMPERATURE

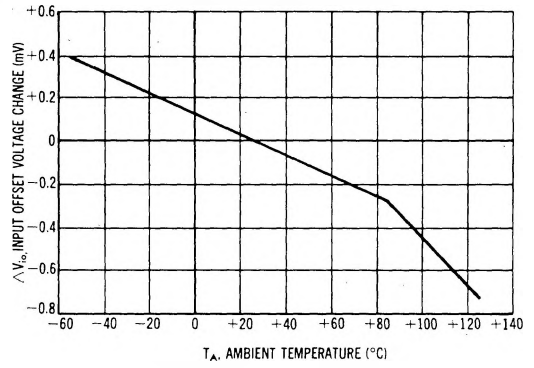
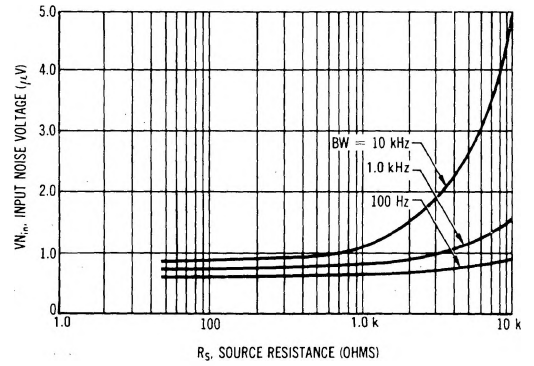


FIGURE 10 – INPUT NOISE VOLTAGE versus SOURCE RESISTANCE



See current MCC1709/1709C data sheet for standard linear chip information.

See current MCBC1709/MCB1709F data sheet for Beam-Lead device information.